BYW80-200

SWITCHMODE [™] **Power Rectifiers**

... designed for use in switching power supplies, inverters and as free wheeling diodes, these state-of-the-art devices have the following features:

- Ultrafast 35 Nanosecond Recovery Time
- 175°C Operating Junction Temperature
- Popular TO-220 Package
- Epoxy Meets UL94, V_O @ 1/8"
- Low Forward Voltage
- Low Leakage Current
- High Temperature Glass Passivated Junction

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 1.9 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 50 units per plastic tube
- Marking: , BYW80-200

MAXIMUM RATINGS

Please See the Table on the Following Page



ON Semiconductor®

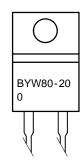
http://onsemi.com

ULTRAFAST RECTIFIERS 8.0 AMPERES 200 V



MARKING DIAGRAM





CASE 221B TO-220AC PLASTIC

BYW80-200 = Device Code

ORDERING INFORMATION

Device	Package	Shipping	
BYW80-200	TO-220	50 Units/Rail	

BYW80-200

MAXIMUM RATINGS

Rating	Symbol	Values	Unit				
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		200	Volts				
Average Rectified Forward Current Total Device, (Rated V _R), T _C = 150°C		8.0	Amps				
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz), T _C = 150°C		16	Amps				
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	100	Amps				
Operating Junction Temperature and Storage Temperature Range	T _J , T _{stg}	-65 to +175	°C				
THERMAL CHARACTERISTICS							
Maximum Thermal Resistance, Junction to Case	$R_{\theta JC}$	3.0	°C/W				
ELECTRICAL CHARACTERISTICS							
Maximum Instantaneous Forward Voltage (Note 1.) $ (i_F = 7.0 \text{ Amps, } T_C = 100^{\circ}\text{C}) \\ (i_F = 22 \text{ Amps, } T_C = 25^{\circ}\text{C}) $	VF	0.85 1.25	Volts				
Maximum Instantaneous Reverse Current (Note 1.) (Rated dc Voltage, $T_J = 100^{\circ}\text{C}$) (Rated dc Voltage, $T_J = 25^{\circ}\text{C}$)	i _R	1 0.01	mA				
Maximum Reverse Recovery Time $ (I_F = 1.0 \text{ Amp, di/dt} = 50 \text{ Amps/}\mu\text{s}) $ $ (I_F = 0.5 \text{ Amp, i}_R = 1.0 \text{ Amp, I}_{REC} = 0.25 \text{ Amp}) $	t _{rr}	35 25	ns				

^{1.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

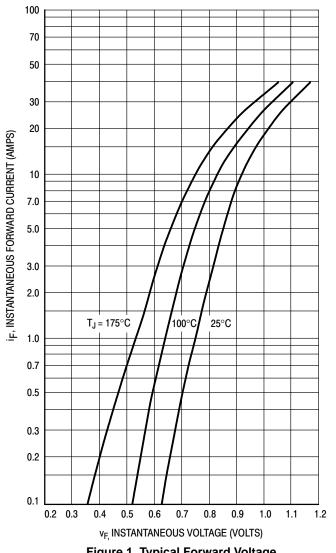


Figure 1. Typical Forward Voltage

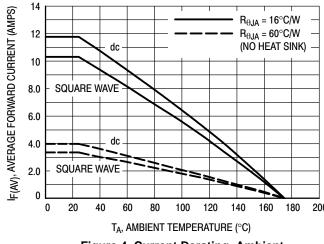


Figure 4. Current Derating, Ambient

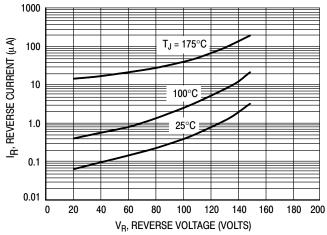


Figure 2. Typical Reverse Current*

* The curves shown are typical for the highest voltage device in the grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if V_R is sufficiently below rated V_R.

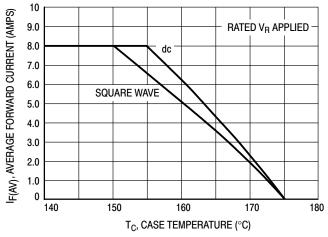


Figure 3. Current Derating, Case

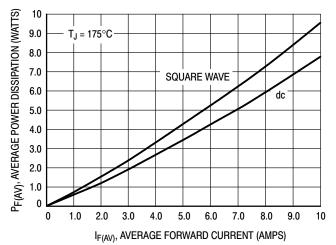


Figure 5. Power Dissipation

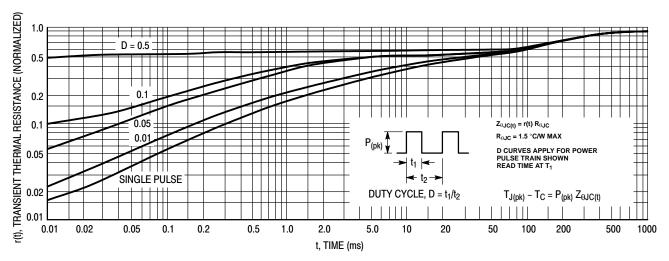


Figure 6. Thermal Response

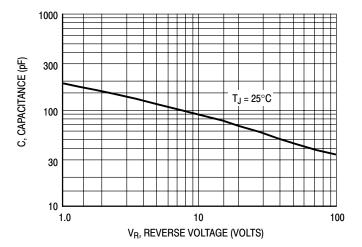
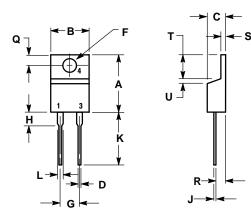


Figure 7. Typical Capacitance

PACKAGE DIMENSIONS

TO-220 TWO-LEAD

CASE 221B-04 ISSUE D



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.595	0.620	15.11	15.75
В	0.380	0.405	9.65	10.29
C	0.160	0.190	4.06	4.82
D	0.025	0.035	0.64	0.89
F	0.142	0.147	3.61	3.73
G	0.190	0.210	4.83	5.33
Н	0.110	0.130	2.79	3.30
_	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.14	1.52
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.14	1.39
Т	0.235	0.255	5.97	6.48
U	0.000	0.050	0.000	1.27

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